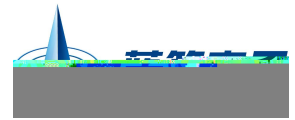


| A | 2020.08.21 |   | LRC-LMUN5313DW1T1G |  |  |
|---|------------|---|--------------------|--|--|
| B | 2021-11-25 | 6 |                    |  |  |
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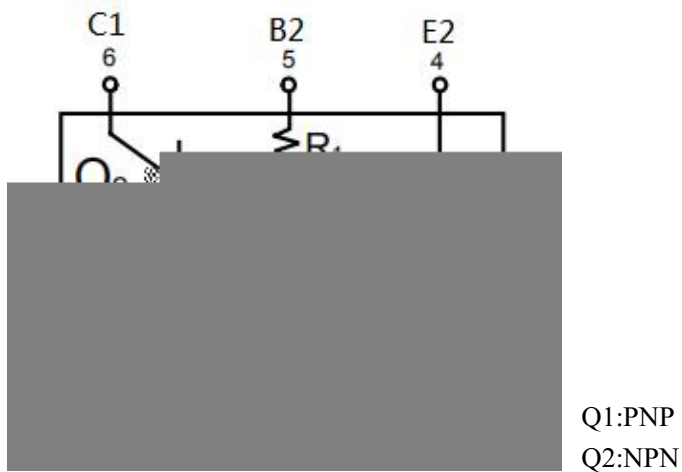
Rev.B Nov.-2021

SOT-363 NPN+PNP

Double silicon NPN and PNP transistor in a SOT-363 Plastic Package

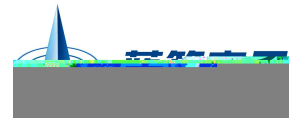
With built-in bias resistors, simplify circuit design, reduce a quantity of parts and manufacturing process, Halogen-free Product.

Switching applications, interface circuit and driver circuit applications.



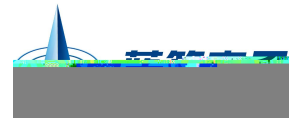
Marking

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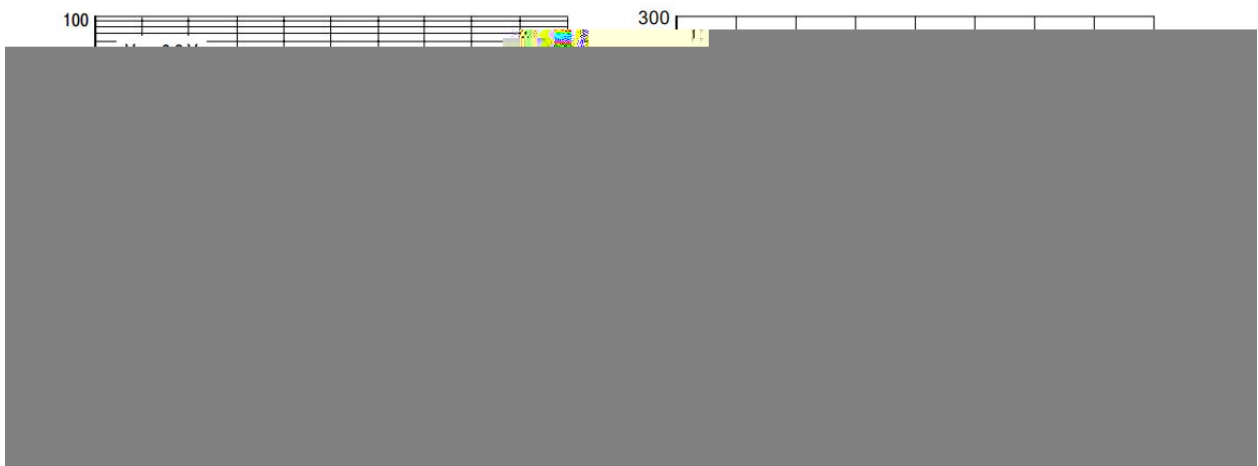
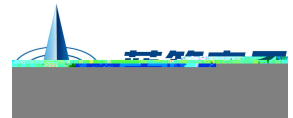
| Parameter                 | Symbol    | Rating  | Unit |
|---------------------------|-----------|---------|------|
| Output Voltage            | $V_{CC}$  | 50      | V    |
| Input Voltage             | $V_{IN}$  | 40      | V    |
|                           |           | -10     | V    |
| Output Current            | $I_{CM}$  | 100     | mA   |
|                           | $I_O$     | 50      | mA   |
| Collector Dissipation     | $P_C$     | 200     | mW   |
| Junction Temperature      | $T_j$     | 150     | °C   |
| Storage Temperature Range | $T_{stg}$ | -55~150 | °C   |

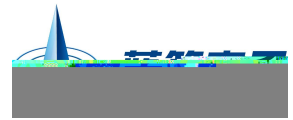
| Parameter              | Symbol       | Test Conditions                         | Min  | Typ | Max  | Unit       |
|------------------------|--------------|-----------------------------------------|------|-----|------|------------|
| Input Voltage          | $V_{I(off)}$ | $V_{CC}=5.0V$ $I_O=100\mu A$            |      |     | 0.5  | V          |
|                        | $V_{I(on)}$  | $V_O=0.3V$ $I_O=2mA$                    | 3    |     |      | V          |
| Output Voltage         | $V_{O(on)}$  | $I_O=10mA$ $I_I=0.5mA$                  |      |     | 0.3  | V          |
| Input Current          | $I_I$        | $V_I=5.0V$                              |      |     | 0.18 | mA         |
| Output Cut-off Current | $I_{O(off)}$ | $V_{CC}=50V$ $V_I=0V$                   |      |     | 0.5  | $\mu A$    |
| DC Current Gain        | $G_I$        | $V_O=5.0V$ $I_O=5.0mA$                  | 68   |     |      |            |
| Transition Frequency   | $f_T$        | $V_{CE}=10V$ $I_E=-5.0mA$<br>$f=100MHz$ |      | 250 |      | MHz        |
| Resistance1            | $R_1$        |                                         | 32.9 | 47  | 61.1 | K $\Omega$ |
| Resistance Ratio       | $R_2/R_1$    |                                         | 0.8  | 1   | 1.2  |            |

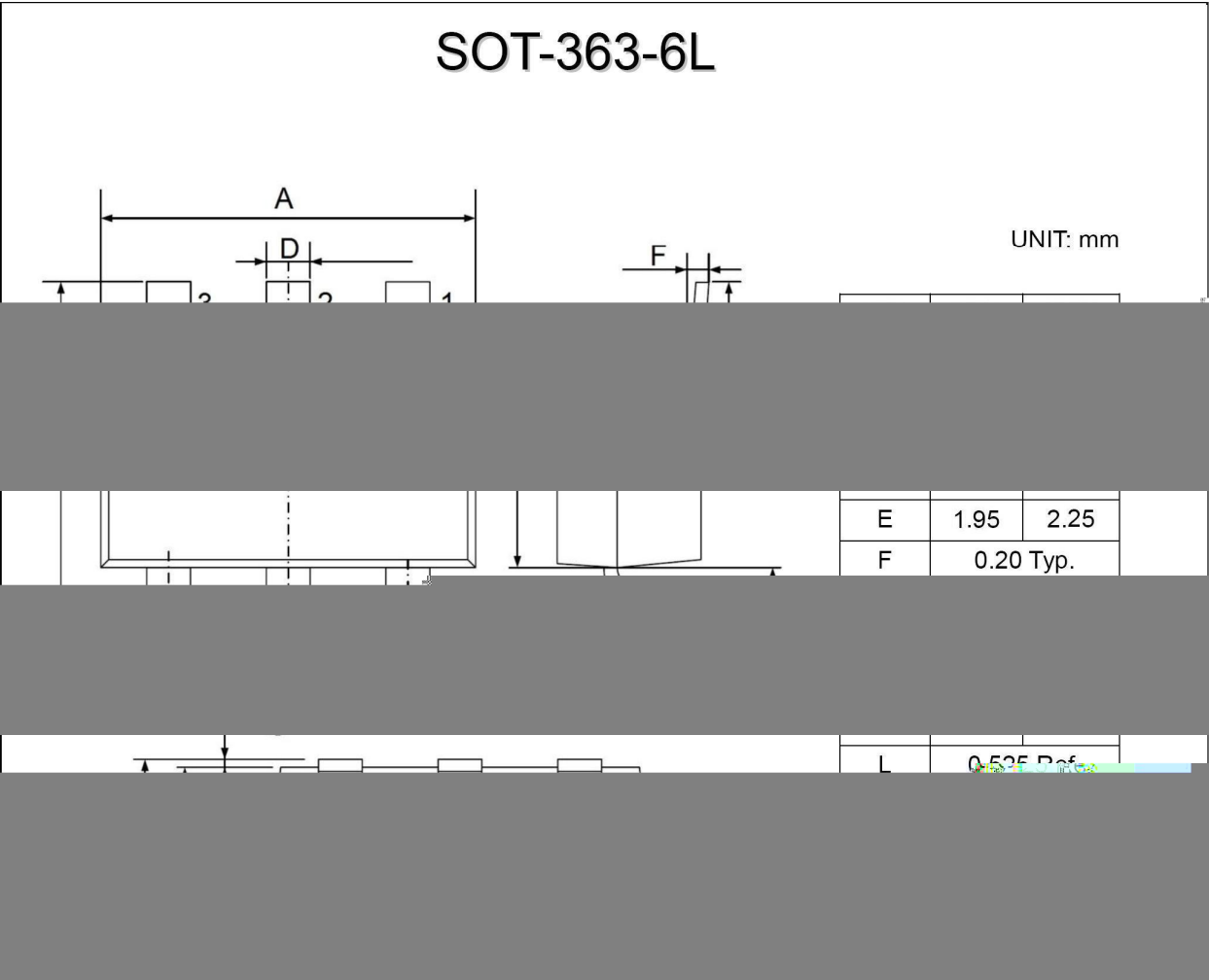


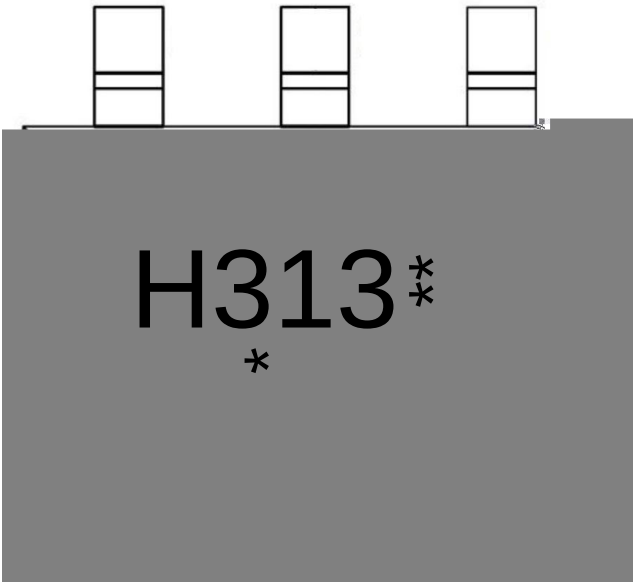
| Parameter                 | Symbol    | Rating  | Unit |
|---------------------------|-----------|---------|------|
| Output Voltage            | $V_{CC}$  | -50     | V    |
| Input Voltage             | $V_{IN}$  | -40     | V    |
|                           |           | 10      | V    |
| Output Current            | $I_C$     | -100    | mA   |
|                           | $I_O$     | -30     | mA   |
| Power Dissipation         | $P_d$     | 200     | mW   |
| Junction Temperature      | $T_j$     | 150     | °C   |
| Storage Temperature Range | $T_{stg}$ | -55~150 | °C   |

| Parameter              | Symbol       | Test Conditions                      | Min  | Typ  | Max   | Unit       |
|------------------------|--------------|--------------------------------------|------|------|-------|------------|
| Input Voltage          | $V_{I(off)}$ | $V_{CC}=-5.0V$ $I_O=-100\mu A$       |      |      | -0.5  | V          |
|                        | $V_{I(on)}$  | $V_O=-0.3V$ $I_O=-2.0mA$             | -3.0 |      |       | V          |
| Output Voltage         | $V_{O(on)}$  | $I_O=-10mA$ $I_i=-0.5mA$             |      | -0.1 | -0.3  | V          |
| Input Current          | $I_i$        | $V_i=-5.0V$                          |      |      | -0.18 | mA         |
| Output Cut-off Current | $I_{O(off)}$ | $V_{CC}=-50V$ $V_i=0V$               |      |      | -0.5  | $\mu A$    |
| DC Current Gain        | $G_i$        | $V_O=-5.0V$ $I_O=-5.0mA$             | 68   |      |       |            |
| Transition Frequency   | $f_T$        | $V_{CE}=-10V$ $f=100MHz$ $I_E=5.0mA$ |      | 250  |       | MHz        |
| Resistance1            | $R_1$        |                                      | 32.9 | 47   | 61.1  | K $\Omega$ |
| Resistance Ratio       | $R_2/R_1$    |                                      | 0.8  | 1.0  | 1.2   |            |









" 1 "

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Note:



"1" Pin

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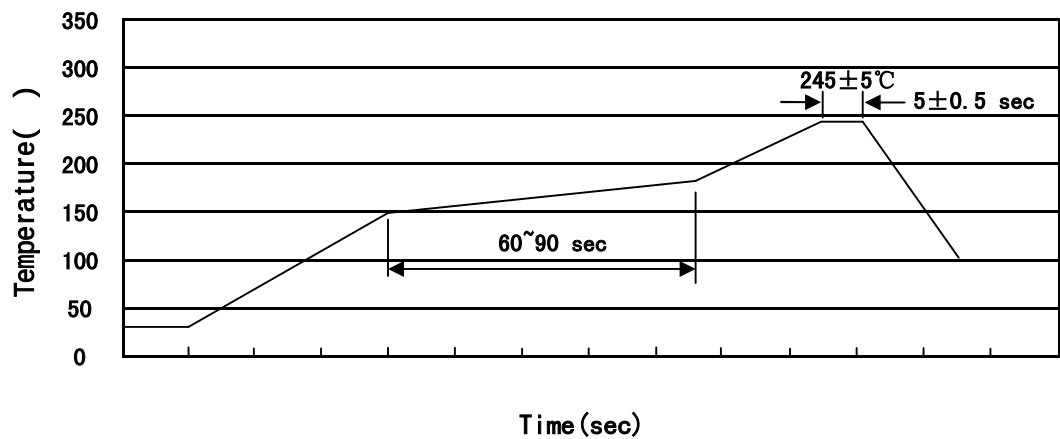
Product Type Code

\*\*\*:

Lot No. Code, code change with Lot No.



Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

1. Preheating: 150~180°C, Time: 60~90sec.
2. Peak Temp.: 245±5°C, Duration: 5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

260±5°C      10±1 sec.      Temp.: 260±5°C      Time: 10±1 sec

/ REEL

| Package Type | Units              |                         |                        |                              |                        | Dimension (unit mm <sup>3</sup> ) |             |             |
|--------------|--------------------|-------------------------|------------------------|------------------------------|------------------------|-----------------------------------|-------------|-------------|
|              | Units/Reel<br>只/卷盘 | Reels/Inner Box<br>卷盘/盒 | Units/Inner Box<br>只/盒 | Inner Boxes/Outer Box<br>盒/箱 | Units/Outer Box<br>只/箱 | Reel                              | Inner Box   | Outer Box   |
| SOT-363      | 3,000              | 10                      | 30,000                 | 6                            | 180000                 | 7" ×8                             | 180×120×180 | 390×385×205 |